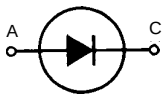
IXYS

Fast Recovery Epitaxial Diode (FRED)

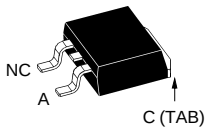
DSEI 8

I_{FAVM} = 8 A
V_{RRM} = 600 V
t_{rr} = 35 ns

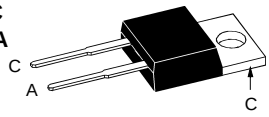
V_{RSM} V	V_{RRM} V	Type
640	600	DSEI 8-06A
640	600	DSEI 8-06AS



TO-263 AA
DSEI 8-06AS



TO-220 AC
DSEI 8-06A



A = Anode, C = Cathode, NC = No connection
TAB = Cathode

Symbol	Test Conditions	Maximum Ratings	
I_{FRMS}	$T_{VJ} = T_{VJM}$	16	A
I_{FAVM} ①	T_C = 115°C; rectangular, d = 0.5	8	A
I_{FRM}	t_P < 10 µs; rep. rating, pulse width limited by T_{VJM}	130	A
I_{FSM}	T_{VJ} = 45°C; t = 10 ms (50 Hz), sine	100	A
	t = 8.3 ms (60 Hz), sine	110	A
	T_{VJ} = 150°C; t = 10 ms (50 Hz), sine	85	A
	t = 8.3 ms (60 Hz), sine	95	A
I^2t	T_{VJ} = 45°C t = 10 ms (50 Hz), sine	50	A^2s
	t = 8.3 ms (60 Hz), sine	50	A^2s
	T_{VJ} = 150°C; t = 10 ms (50 Hz), sine	36	A^2s
	t = 8.3 ms (60 Hz), sine	37	A^2s
T_{VJ}		-40...+150	°C
T_{VJM}		150	°C
T_{stg}		-40...+150	°C
P_{tot}	T_C = 25°C	50	W
M_d	Mounting torque	0.4...0.6	Nm
Weight		2	g

Symbol	Test Conditions	Characteristic Values typ.	max.	
I_R	T_{VJ} = 25°C $V_R = V_{RRM}$		20	µA
	T_{VJ} = 25°C $V_R = 0.8 \cdot V_{RRM}$		10	µA
	T_{VJ} = 125°C $V_R = 0.8 \cdot V_{RRM}$		1.5	mA
V_F	I_F = 8 A; T_{VJ} = 150°C		1.3	V
	T_{VJ} = 25°C		1.5	V
V_{T0}	For power-loss calculations only		0.98	V
r_T	$T_{VJ} = T_{VJM}$		28.7	mΩ
R_{thJC}			2.5	K/W
R_{thCK}		0.5		K/W
R_{thJA}			60	K/W
t_{rr}	I_F = 1 A; -di/dt = 50 A/µs; V_R = 30 V; T_{VJ} = 25°C	35	50	ns
I_{RM}	V_R = 350 V; I_F = 8 A; $-di_F/dt$ = 64 A/µs; L ≤ 0.05 µH; T_{VJ} = 100°C	2.5	2.8	A

Features
- International standard package JEDEC TO-220 AC & TO-263 AB
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low I_{RM}-values
- Soft recovery behaviour
- Epoxy meets UL 94V-0

Applications
- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Advantages
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

① I_{FAVM} rating includes reverse blocking losses at T_{VJM}, $V_R = 0.8\ V_{RRM}$, duty cycle d = 0.5
Data according to IEC 60747
IXYS reserves the right to change limits, test conditions and dimensions

033

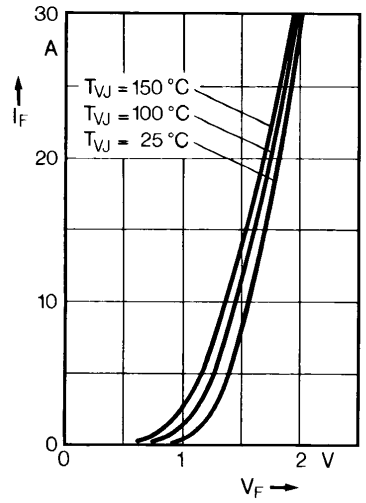


Fig. 1 Forward current versus voltage drop.

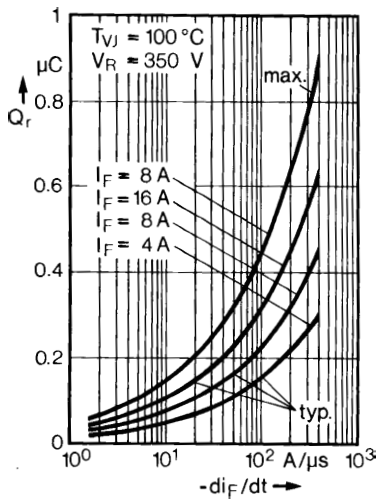


Fig. 2 Recovery charge versus $-di_F/dt$.

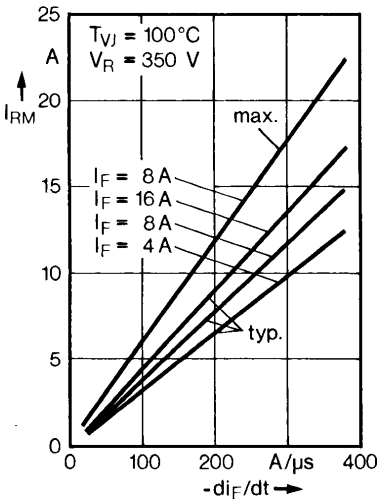


Fig. 3 Peak reverse current versus $-di_F/dt$.

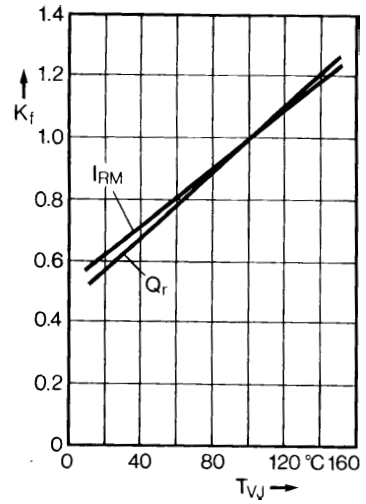


Fig. 4 Dynamic parameters versus junction temperature.

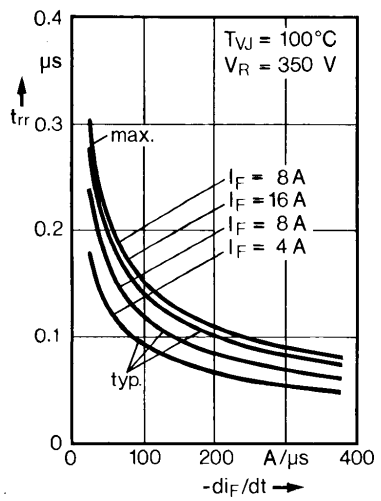


Fig. 5 Recovery time versus $-di_F/dt$.

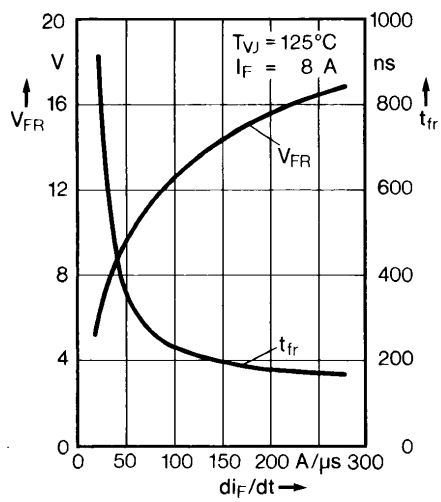


Fig. 6 Peak forward voltage versus di_F/dt.

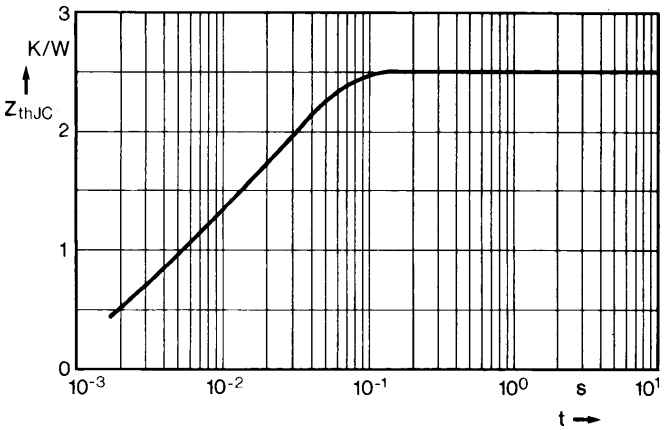
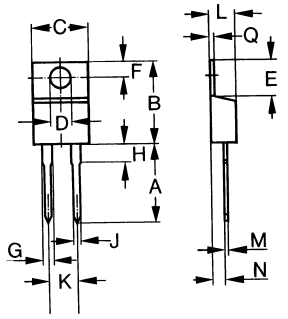


Fig. 7 Transient thermal impedance junction to case.

Dimensions TO-220 AC



Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	12.70	14.73	0.500	0.580
B	14.23	16.51	0.560	0.650
C	9.66	10.66	0.380	0.420
D	3.54	4.08	0.139	0.161
E	5.85	6.85	0.230	0.420
F	2.54	3.42	0.100	0.135
G	1.15	1.77	0.045	0.070
H	-	6.35	-	0.250
J	0.64	0.89	0.025	0.035
K	4.83	5.33	0.190	0.210
L	3.56	4.82	0.140	0.190
M	0.38	0.56	0.015	0.022
N	2.04	2.49	0.080	0.115
Q	0.64	1.39	0.025	0.055

Dimension TO-263 AA see DSEI 19

033